

R S COMPONENTS LTD

查询"307-963"供应商

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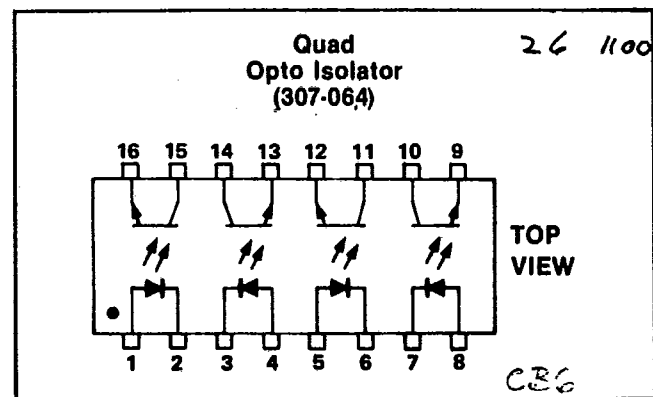
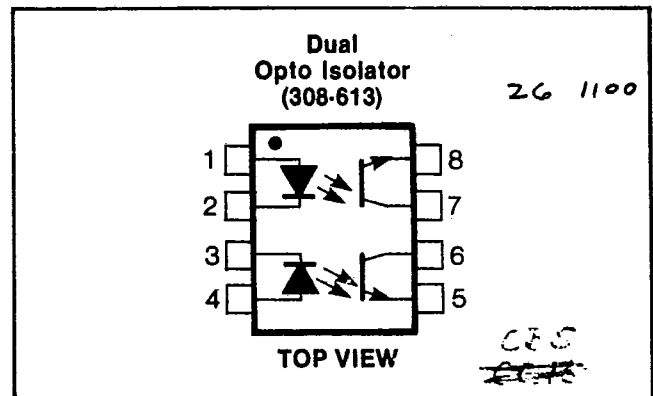
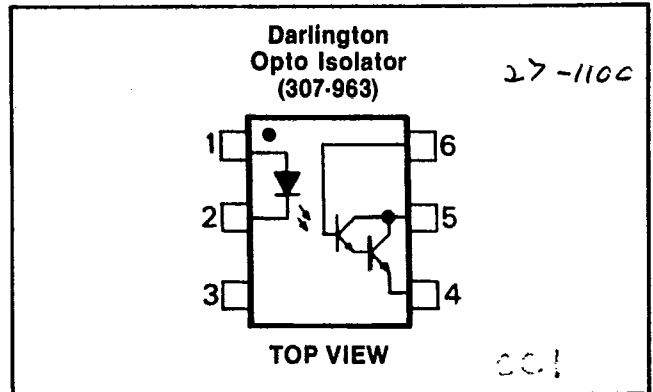
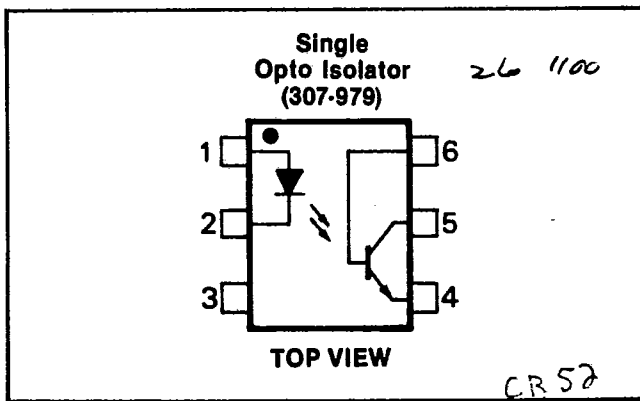
# Opto isolators and opto coupled SCR/triacs

*new*  
*RSCB*  
*030085*

*T-41-83*  
*T-41-85*  
*T-41-87*

Four infra-red light emitting diode and silicon phototransistor couplers consisting of: (1) A single Opto Isolator in dual-in-line package suited for fast signal transfer and offering excellent noise immunity. (2) A single Opto Isolator also in a 6 pin dual-in-line package suited for fast signal transfer and offering a high transfer ratio and a darlington transistor output for greater drive capability which will respond to low power signal sources. (3) A dual Opto Isolator having two isolated light emitting diode-photo transistor couplers in one 8 pin dual-in-line Package. (4) A quad Opto Isolator having 4 isolated light emitting diode-photo transistor couplers in one 16 pin dual-in-line package. These last two items offer space and cost saving when multiple isolation is required. In addition an opto-coupled SCR and two opto-coupled triacs are available in 6-pin DIL packages. See pages 4 and 5. All of these couplers offer high voltage and AC isolation and are suited for interface applications in TTL and analogue circuits.

## Phototransistor opto isolators Pin configurations



Ratings	Single Opto Isolator (307-979)	Darlington Opto Isolator (307-963)	Dual Opto Isolator (308-613)	Quad Opto Isolator (307-064)
Isolation voltage (dc)	±4000V	±4000V	±1500V	±1500V
V <sub>CE</sub> (max) Transistor (dc)	30V	30V	30V	30V
I <sub>F</sub> (max) Diode (dc)	60mA	60mA	100mA	100mA
DC Current transfer Ratio (min)	20%	300%	12.5%	12.5%
	6-pin DIL packages with transistor connection for biasing.		8-pin DIL package	16-pin DIL package

Absolute maximum ratings <a href="#">查询"307-963"供应商</a>	Single Opto Isolator (307-979)	Darlington Opto Isolator (307-963)	Dual Opto Isolator (308-613)	Quad Opto Isolator (307-064)	Unit
T <sub>A</sub> TEMPERATURE RANGE	-50 to +100	-50 to +100	-55 to +100	-55 to +100	°C
V I/O ISOLATION	±4000	±4000	±1500	±1500	V
I <sub>F</sub> DIODE	60	60	100	100	mA
V <sub>R</sub> DIODE	3	3	3	3	V
P <sub>d</sub> DIODE derate at 1.33mW/°C>25°C	100	100	150	150	mW
V <sub>CEO</sub>	30	30	30	30	V
V <sub>ECO</sub>	5	5	7	7	V
P <sub>d</sub> TRANSISTOR derate at 2.0mW/°C>25°C	150	150	150	150	mW
TOTAL PACKAGE DISSIPATION derate at 5.33mW/°C>25°C	—	—	400	—	mW
derate at 6.67mW/°C>25°C	—	—	—	500	mW

Electrical characteristics Ta = 25°C

T-41-87

Parameter	Test conditions	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Units
<b>DIODE</b>														
V <sub>F</sub>	I <sub>F</sub> = 10mA I <sub>F</sub> = 20mA	—	—	1.5	—	—	1.5	—	—	—	—	—	—	V
I <sub>R</sub>	I <sub>F</sub> = 100mA V <sub>R</sub> = 3V	—	—	10	—	—	100	—	—	1.3	—	—	1.3	V
<b>TRANSISTOR</b>														
BV <sub>CEO</sub>	I <sub>C</sub> = 1mA I <sub>C</sub> = 100μA	30	—	—	30	—	—	10	—	—	10	—	—	V
BV <sub>ECO</sub>	I <sub>E</sub> = 10μA I <sub>E</sub> = 100μA	5	—	—	5	—	—	—	—	—	—	—	—	V
BV <sub>CBO</sub>	I <sub>C</sub> = 10μA	70	—	—	—	30	—	—	—	—	—	—	—	V
I <sub>CEO</sub> DARK CURRENT	V <sub>CE</sub> = 5V I <sub>F</sub> = 0 V <sub>CE</sub> = 10V I <sub>F</sub> = 0 H = 0	—	5	50	—	—	100	—	5	500	—	5	500	nA
I <sub>CBO</sub>	V <sub>CE</sub> = 10V I <sub>E</sub> = 0	—	—	20	—	—	50	—	—	—	—	—	—	nA
h <sub>FE</sub>	V <sub>CE</sub> = 5V I <sub>C</sub> = 100μA	100	200	—	—	20k	—	—	—	—	—	—	—	nA
C <sub>CE</sub>	V <sub>CE</sub> = 0	—	8	—	—	5	—	—	2	—	—	2	—	pF
<b>COUPLED</b>														
I <sub>C</sub> /I <sub>F</sub> DC CURRENT TRANSFER RATIO	I <sub>F</sub> = 10mA V <sub>CE</sub> = 2V I <sub>F</sub> = 16mA V <sub>CE</sub> = 5V	20	—	—	300	—	—	12.5	35	—	12.5	35	—	%
R <sub>ISO</sub> ISOLATION RESISTANCE	V = 500V	10 <sup>11</sup>	—	—	10 <sup>11</sup>	—	—	—	10 <sup>11</sup>	—	—	10 <sup>11</sup>	—	Ω
V <sub>CE(SAT)</sub>	I <sub>F</sub> = 10mA I <sub>C</sub> = 10mA I <sub>F</sub> = 16mA I <sub>C</sub> = 2mA	—	—	0.4	—	1	—	—	0.5	—	—	—	0.5	V
C I/O INPUT/OUTPUT CAPACITANCE		—	2	—	—	0.5	—	—	0.5	—	—	0.5	—	pF
t <sub>r</sub> RISE TIME	V <sub>CE</sub> = 10V, I <sub>B</sub> = 0, I <sub>F</sub> = 10mA V <sub>CE</sub> = 10V, R <sub>L</sub> = 100Ω, I <sub>F</sub> = 10mA	—	2	—	—	—	—	—	—	—	—	—	—	μs
t <sub>f</sub> FALL TIME	V <sub>CE</sub> = 10V, I <sub>B</sub> = 0, I <sub>F</sub> = 10mA V <sub>CE</sub> = 10V, R <sub>L</sub> = 100Ω, I <sub>F</sub> = 8mA	—	2	—	—	—	—	—	2	—	—	2	—	μs
	V <sub>CE</sub> = 10V, R <sub>L</sub> = 100Ω, I <sub>F</sub> = 10mA	—	—	—	—	25	—	—	—	—	—	—	—	μs
	V <sub>CE</sub> = 10V, R <sub>L</sub> = 100Ω, I <sub>C</sub> = 8mA	—	—	—	—	—	—	—	2	—	—	2	—	μs

Figure 1 Response time vs base resistance for 307-979

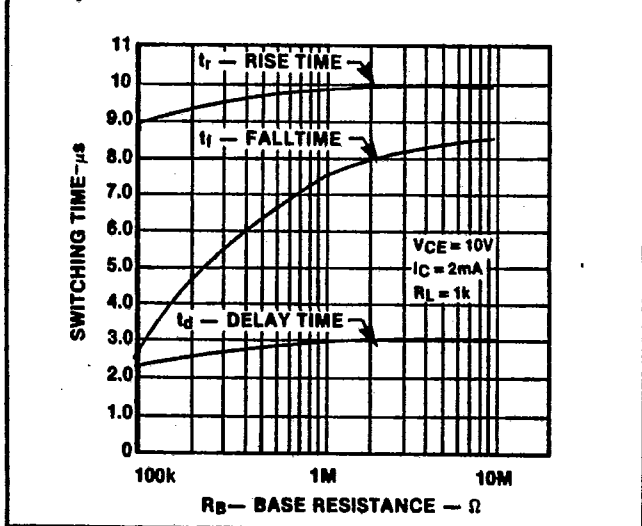
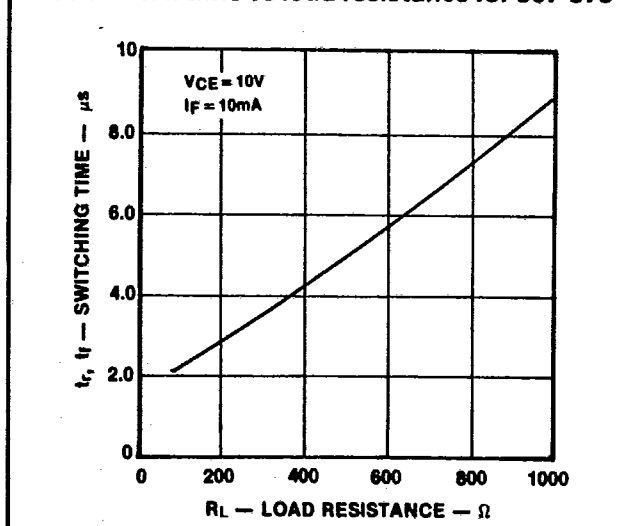


Figure 2 Rise and fall time vs load resistance for 307-979

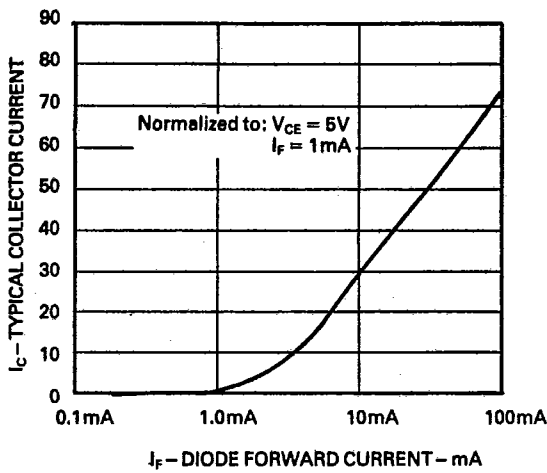


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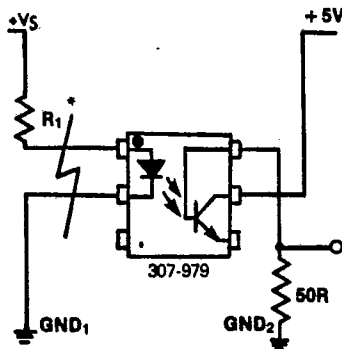
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Figure 3 Typical collector current vs diode forward current for 307 & 963



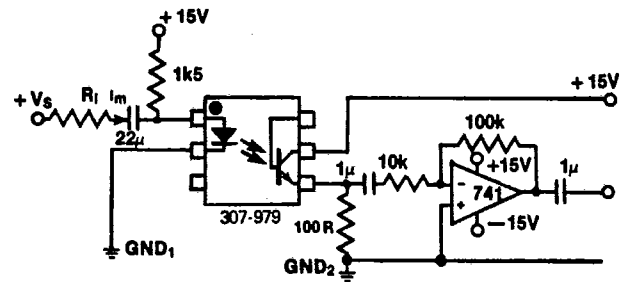
Applications

Figure 4 Fast pulse transfer



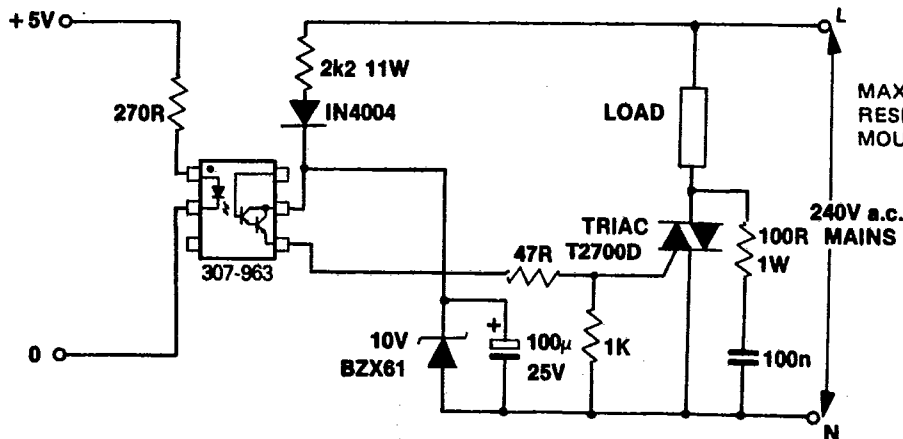
This mode of operation increases switching speed from about 2 $\mu$ s to about 100ns but reduces current transfer ratio to about 0.2%

Figure 5 A.C. signal isolation



Choose  $R_1$  to limit modulating current ( $I_m$ ) to 5mA max. Useful frequency range in the order of 20Hz to 20kHz

Figure 6 Light activated solid state relay



MAXIMUM LOAD:- 540W  
RESISTIVE/INDUCTIVE LOAD 6A  
MOUNT TRIAC ON A 4°C/W HEAT SINK.

3958

Figure 7 **TTL interface** [查询 307-063 供应商](#)

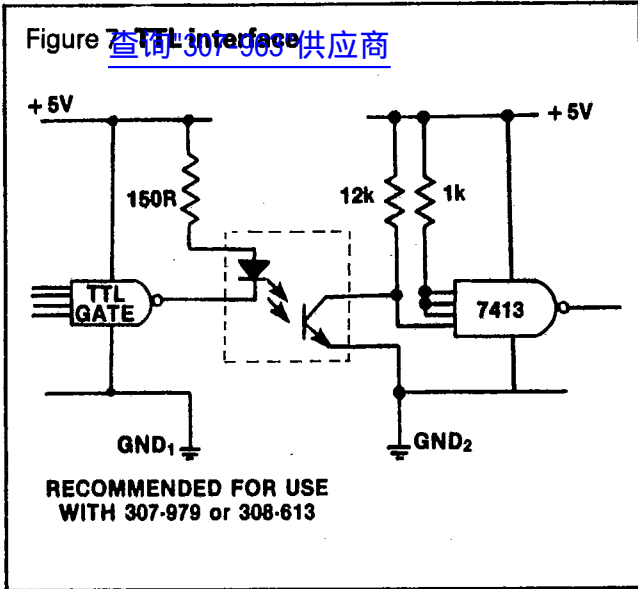
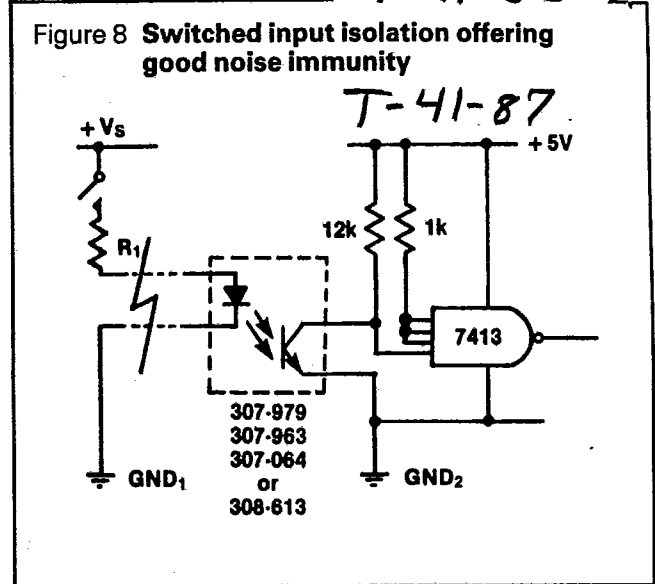


Figure 8 **Switched input isolation offering good noise immunity**



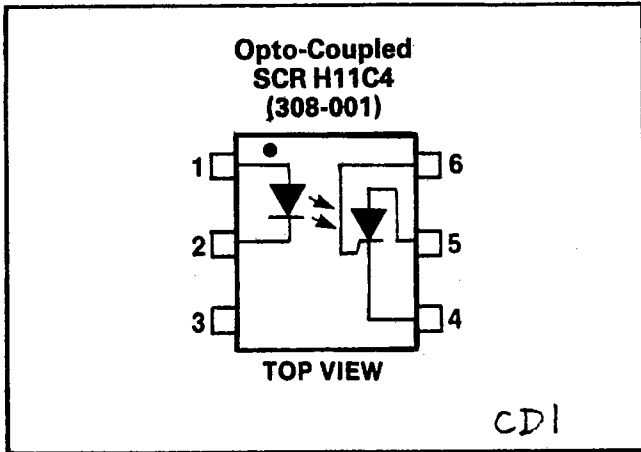
NOTE: \*R<sub>1</sub> is chosen to limit I<sub>F</sub>,  $R_1 = \frac{V_s - V_F}{I_F}$

Where V<sub>F</sub>—forward volts drop of diode  
I<sub>F</sub>—forward diode current  
V<sub>s</sub>—supply voltage

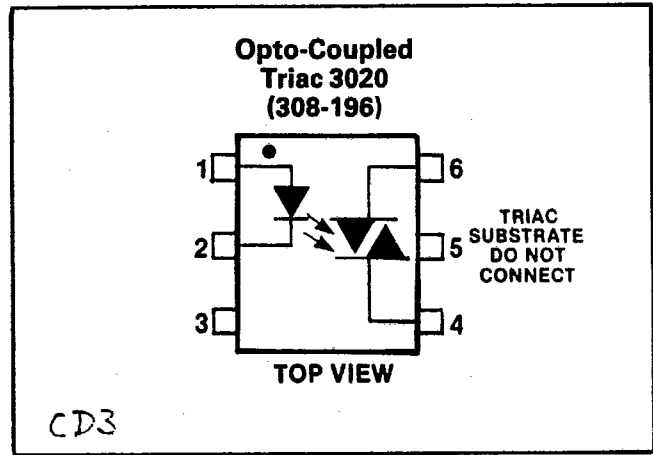
### Opto-coupled SCR and Triacs

A gallium arsenide infra-red light emitting diode coupled with a light activated silicon controlled rectifier or triac in a 6 pin dual-in-line package.

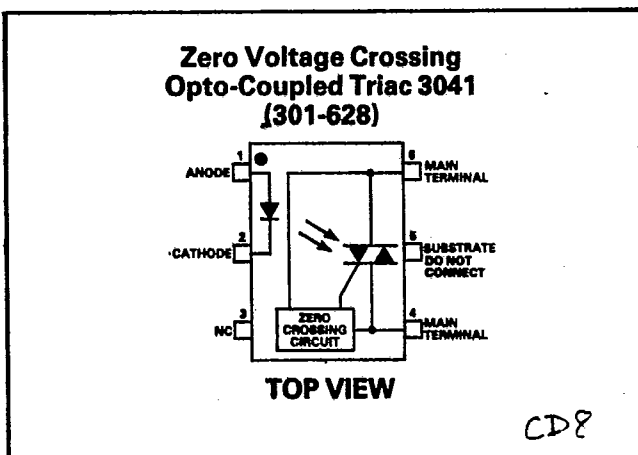
OE 28 1100



OE 28 1200



OE 28 1200



Electrical characteristics  $T_A = 25^\circ\text{C}$  unless otherwise stated

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	308-001			308-196			301-628			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
<b>LED</b>										
$V_F$ (at $I_F = 10\text{mA}$ )	-	1.2	1.5	-	1.2	1.5	-	1.2	1.5	V
$I_R$ (at $V_R = 3\text{V}$ )	-	-	10	-	0.05	100	-	-	100	$\mu\text{A}$
<b>Output switch (SCR or triac)</b>										
$V_{DRM}$	400	-	-	400	-	-	400	-	-	V
$V_{RRM}$	400	-	-	400	-	-	400	-	-	V
$V_{TM}$	-	1.1	1.3	-	2.5	3.0	-	1.75	3.0	V
		$(I_{TM} = 0.3\text{A})$			$(I_{TM} = 0.1\text{A})$					
$I_{DRM}$ (at $400\text{V } V_{DRM}$ )	-	-	150	-	0.01	0.1	-	0.01	0.1	$\mu\text{A}$
			$(T_A = 100^\circ\text{C})$							
$I_H$	-	100	-	-	100	-	-	200	-	$\mu\text{A}$
		$(R_{GK} = 10\text{k}\Omega,$ $V_{AK} = 50\text{V})$			$(V_{AK} = 3\text{V})$					
$\frac{dV}{dt}$	-	20	-	-	2	-	-	100	-	$\text{V}/\mu\text{s}$
		$(R_{GK} = 10\text{k}\Omega)$								
<b>Total device</b>										
LED current to latch O/P switch	-	-	20	-	8	15	-	-	-	mA
		$(V_{AK} = 50\text{V}, R_{GK} = 10\text{k}\Omega)$								
		11								
		$(V_{AK} = 100\text{V}, R_{GK} = 27\text{k}\Omega)$			$(V_{AK} = 3.0\text{V}, 10\text{mA}$ LED Drive)					
<b>Isolation</b>					Surge voltage (5s) 7,500V Peak					

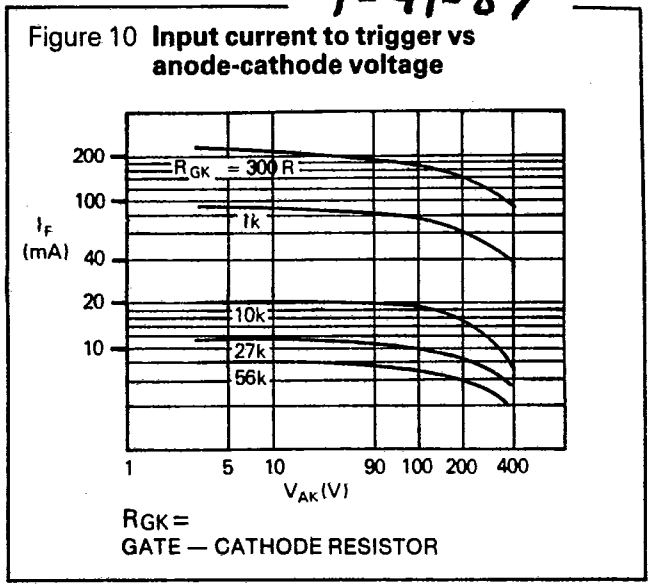
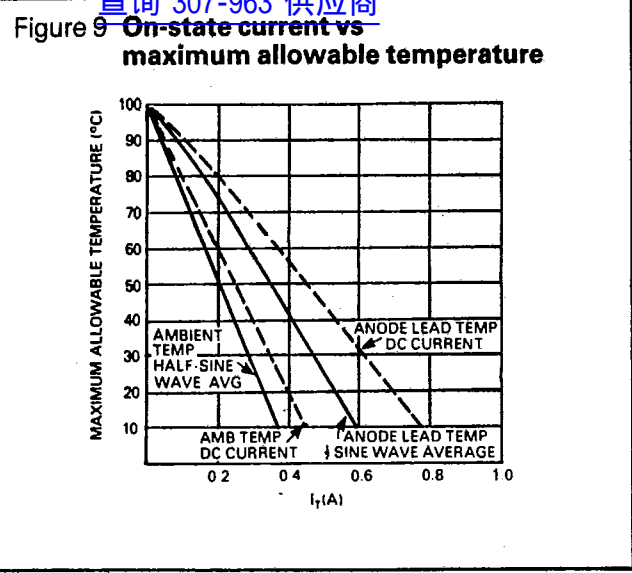
Absolute maximum ratings

L.E.D.	308-001	308-196	301-628
Continuous forward current	60mA	50mA	50mA
Reverse voltage	6V	3V	6V
<b>Output switch (SCR or triac)</b>			
$V_{DRM}$	400V	400V	400V
$V_{RRM}$	400V	400V	400V
$I_{T(RMS)}$	300mA	100mA	50mA
$I_{TSM}$	5A	1.2A	1.2A
	[ 100 $\mu\text{s}$ pulse 1% duty cycle ]	[ 10 $\mu\text{s}$ pulse 10% duty cycle ]	[ 10ms pulse 10% duty cycle ]
$P_D$ at $T_A = 25^\circ\text{C}$	400mW Derate 5.3 mW/ $^\circ\text{C}$ above $25^\circ\text{C}$	300mW Derate 4 mW/ $^\circ\text{C}$ above $25^\circ\text{C}$	330mW Derate 4.4 mW/ $^\circ\text{C}$ above $25^\circ\text{C}$

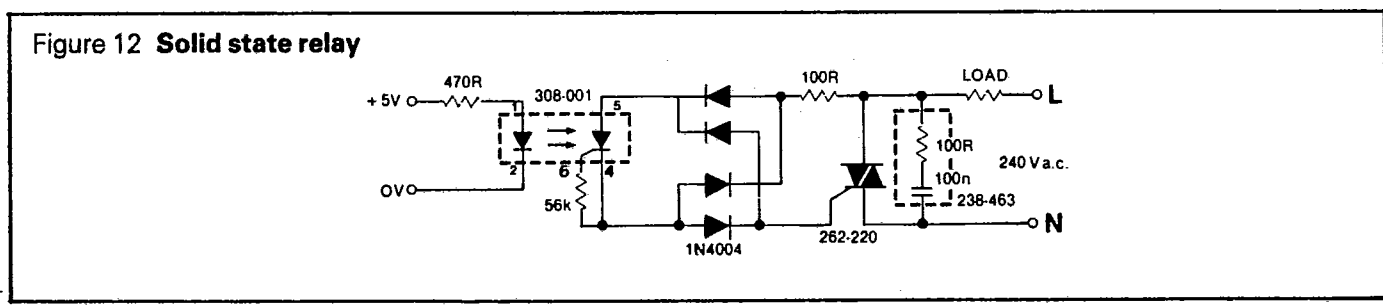
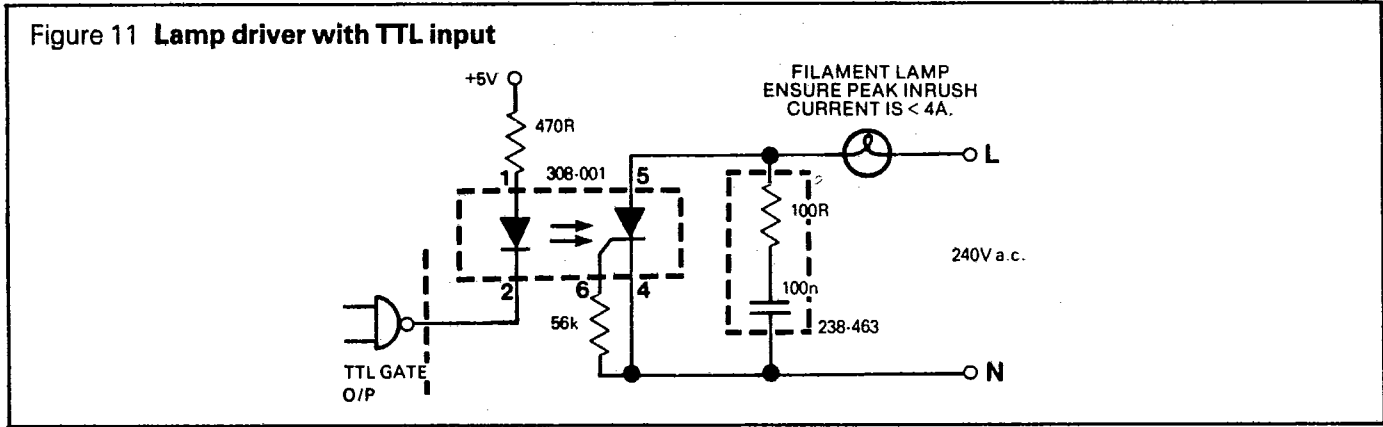
T-41-83  
T-41-85  
T-41-87

### 3958 Opto-coupled SCR

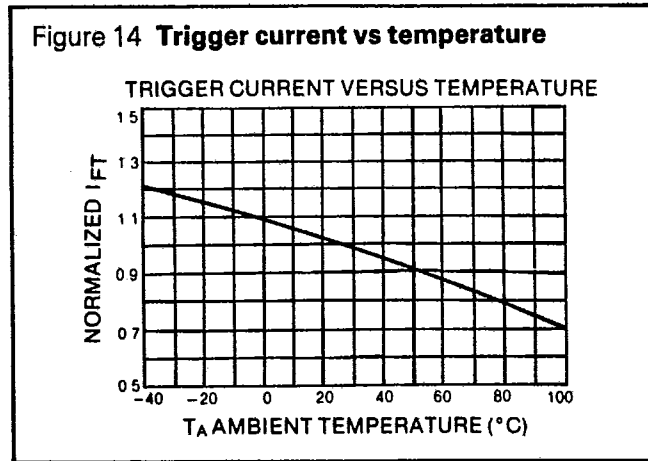
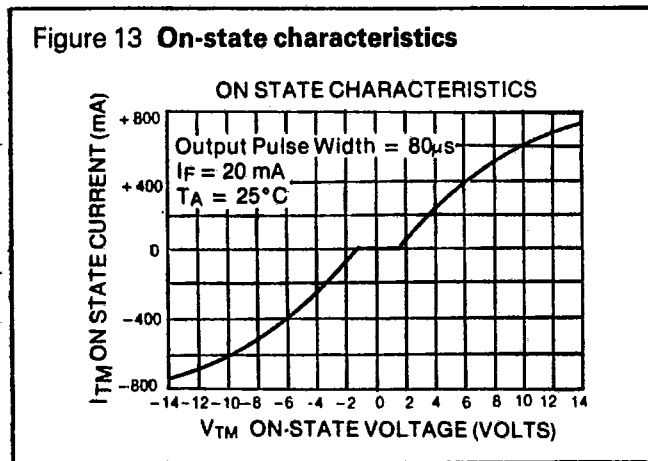
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### Applications



### Opto-coupled triac



Applications

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Figure 15 Resistive load with TTL input

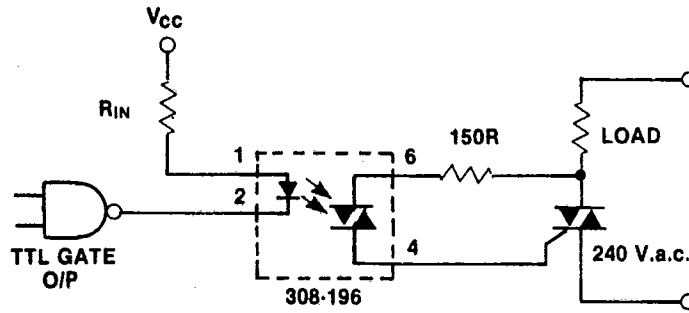
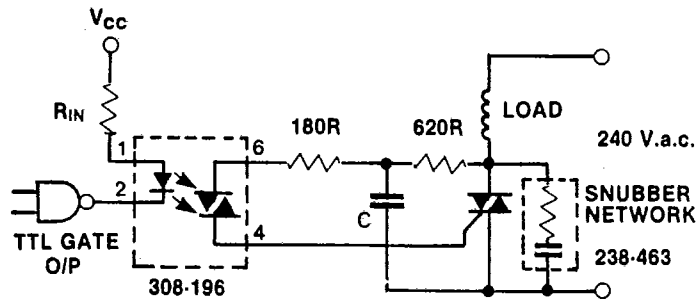
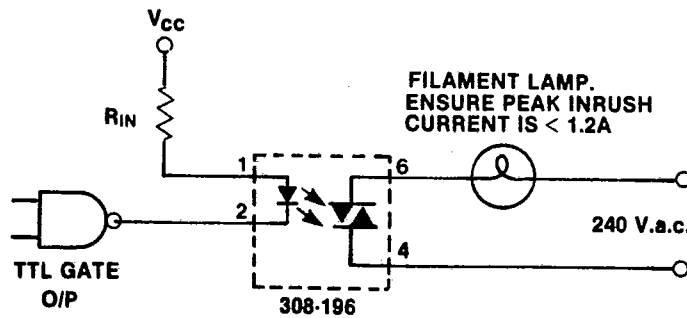


Figure 16 Inductive load with TTL input



C	LOAD POWER FACTOR
220n	0.75
330n	0.5

Figure 17 Low power filament lamp driver with TTL input





Zero voltage crossing opto-coupled triac

Figure 18 Trigger current vs temperature

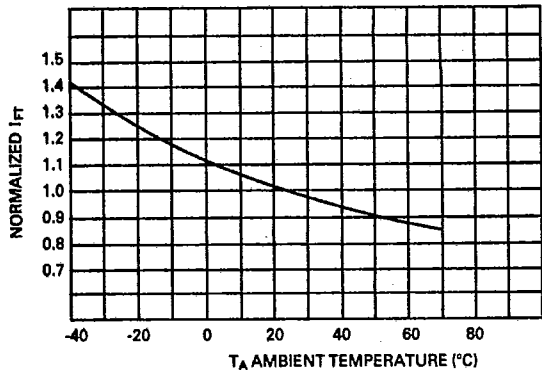
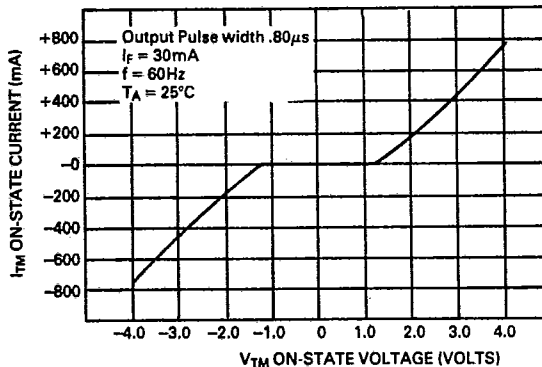


Figure 19 On-state characteristics



Applications

Figure 20 Mains switching

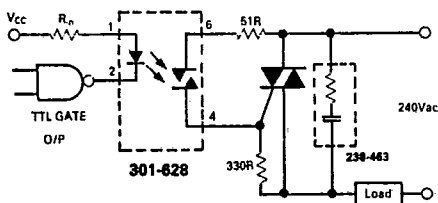


Figure 21 Inverse - parallel SCR driver circuit

